

**10A 1200V SiC Schottky Diode**
**■ Applications**

- Switch Mode Power Supply
- Power Factor Correction
- Solar Inverter
- Uninterruptible Power Supply

**■ Features**

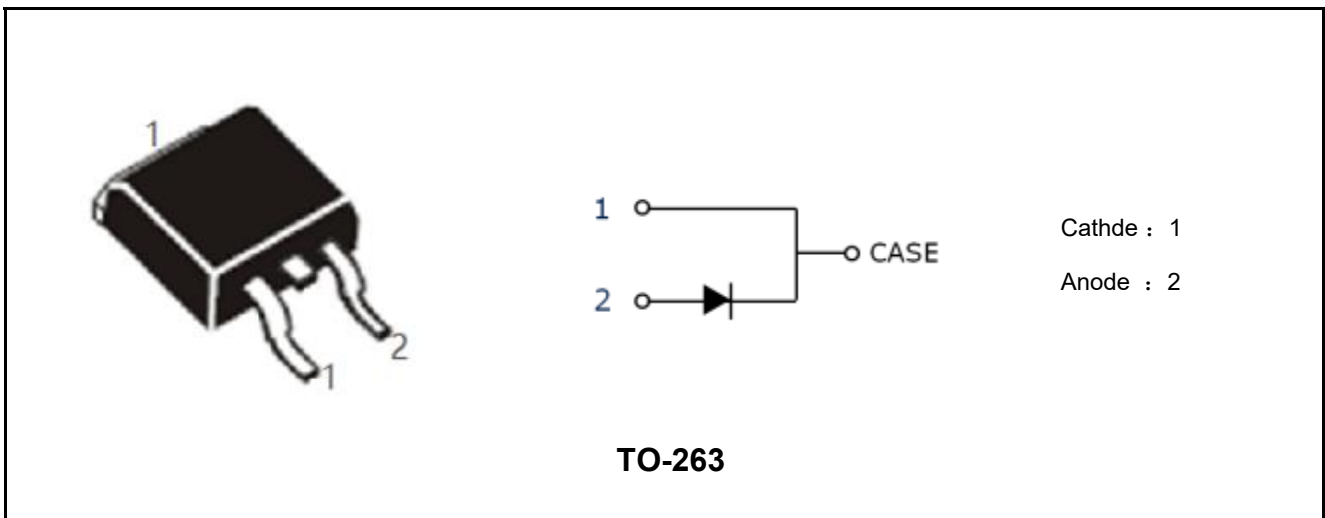
- No Reverse Recovery/ No Forward Recovery
- Temperature Independent Switching Behavior
- Positive Temperature Coefficient on  $V_F$
- Fast Reverse Recovery
- High Surge Current Capability
- 100% UIS and RG Tested

**■ Product Summary**

$V_{RRM}$	1200	V
$I_F@T_c=160^\circ\text{C}$	10	A
$V_{F,TYP}@T_c=25^\circ\text{C}$	1.41	V
$V_{F,TYP}@T_c=175^\circ\text{C}$	2.0	V
$Q_C$	52	nC

**■ Benefits**

- Higher System Efficiency
- System Cost and Size Savings
- High Frequency Operation
- Higher System Reliability
- Reduced EMI



Marking	Package	Packaging	Min. package quantity
ML3S10C120	TO-263	Tube	1000
ML3S10C120	TO-263	Tape & Reel	800



**■ Absolute Maximum Ratings (Tc=25°C unless otherwise noted)**

Parameter	Symbol	Ratings	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	1200	V
Surge Peak Reverse Voltage	$V_{RSM}$	1200	V
DC Peak Blocking Voltage	$V_R$	1200	V
Continuous Forward Current	$I_F$	10	A
Tc=160°C			
Non-Repetitive Peak Forward Surge Current	$I_{FSM}$	64	A
Power Dissipation	$P_D$	100	W
Junction Temperature	$T_J$	175	°C
Storage Temperature	$T_{stg}$	-55-175	°C

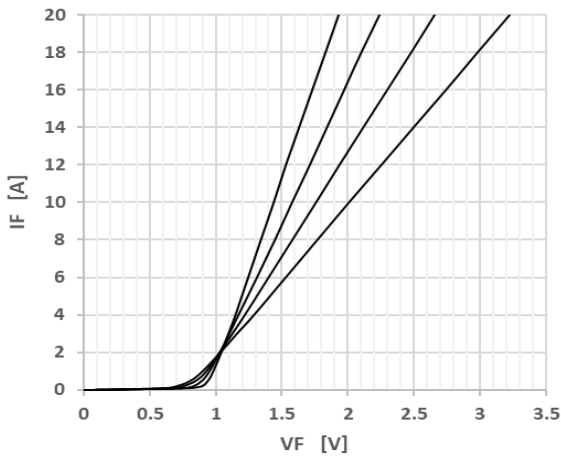
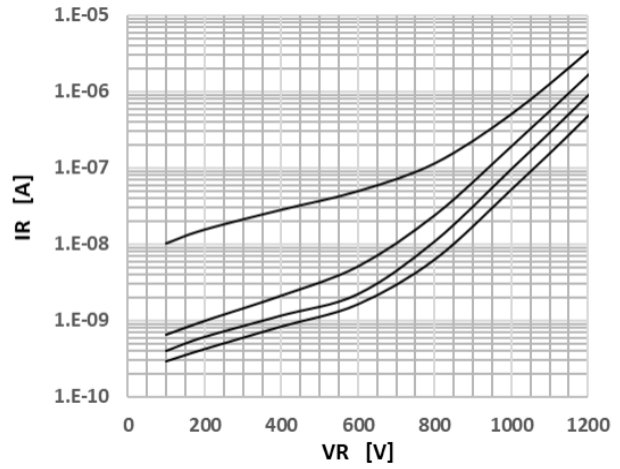
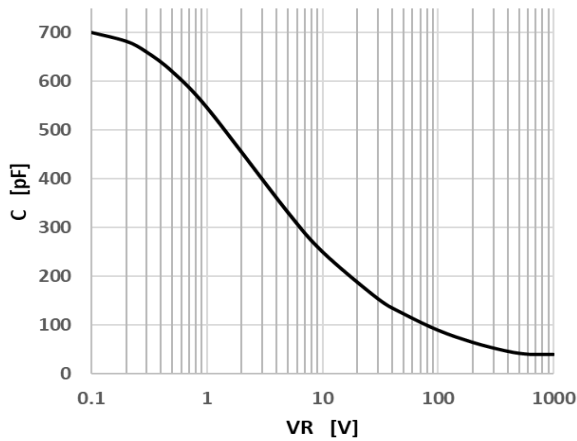
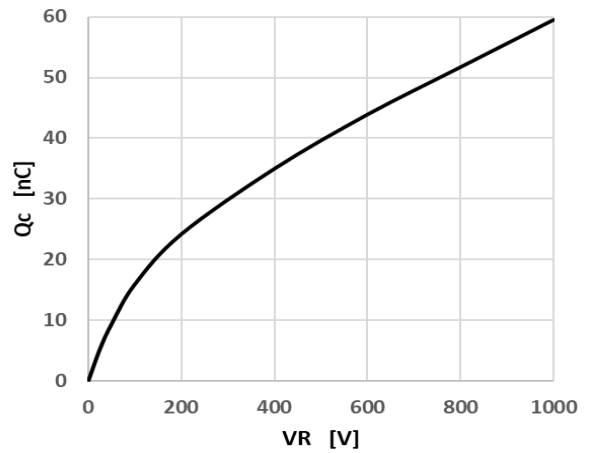
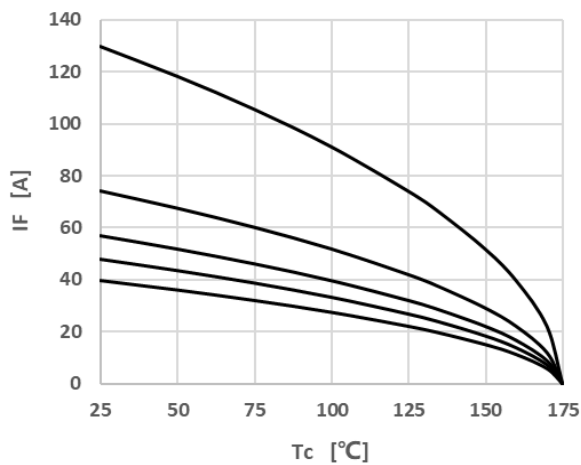
**■ Thermal Characteristics**

Parameter	Symbol	Max	Unit
Maximum Junction-to-Case	$R_{\theta JC}$	1.5	°C/W
Maximum Junction-to-Ambient	$R_{\theta JA}$	60	°C/W

**■ Electrical Characteristics (Tc=25°C unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Static Parameters</b>						
DC Blocking Voltage	$V_{DC}$	$I_R=100\mu A$	1200	-	-	V
Forward Voltage	$V_F$	$I_F=10A$	-	1.41	1.7	V
		$I_F=10A, T_J=175^\circ C$	-	2		V
Reverse Current	$I_R$	$V_R=1200V$	-	0.5	20	$\mu A$
		$V_R=1200V, T_J=175^\circ C$	-	4	100	$\mu A$
<b>AC Parameters</b>						
Total Capacitive Charge	$Q_C$	$I_F=10A, di/dt=400A/\mu s, V_R=400V, T_J=25^\circ C$	-	52	-	nC
Total Capacitive	C	$V_R=1V, f=1MHz$	-	545	-	pF
		$V_R=400V, f=1MHz$	-	45	-	
		$V_R=800V, f=1MHz$	-	40	-	



**■ Characteristics Curves**

**Forward Characteristics**

**Reverse Characteristics**

**Capacitance**

**Recovery Charge vs. Reverse Voltage**

**Current Derating**


**■ TO-263 Package Dimensions**

Unit: mm

Symbol	Min	Nom	Max	Symbol	Min	Nom	Max
A	4.42		4.72	e1	2.44	2.54	2.64
B	1.22		1.4	e2	4.98		5.18
b	0.76		0.86	L1	14.7	15.1	15.5
b1	1.22		1.4	L2	2	2.3	2.6
b2	0.33		0.43	L3	1.5		2
C	1.22		1.35	K	-0.1		0.1
D	9.95		10.25	Y	8.51	8.61	8.71
E	8.99		9.29				

